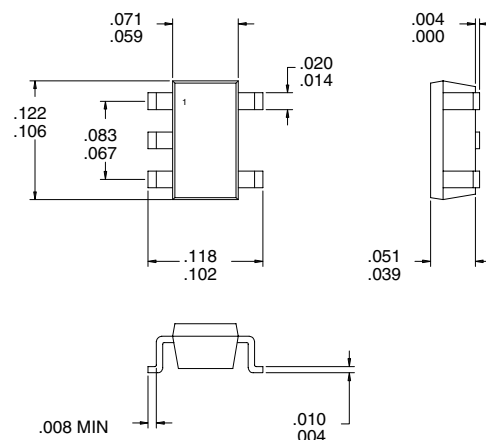


Typical Applications

- DCS GSM
- PCS CDMA
- PCS TDMA
- 2.4GHz Systems
- General Purpose Amplification
- Commercial and Consumer Systems

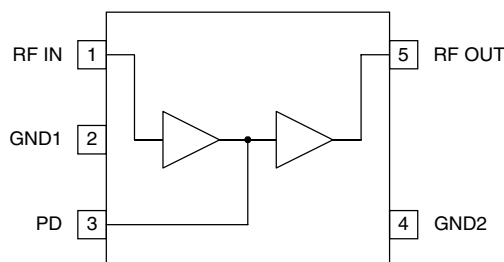
Product Description

The RF2365 is a low noise amplifier with a high dynamic range designed for the receive front end of digital cellular applications at PCS/DCS frequencies. It is designed to amplify low level signals with minimum noise contribution while operating in the harsh, interference-rich environments of newly deployed digital subscriber units. The part provides excellent performance as a LNA for 2.4GHz radio applications. The IC is featured in a standard SOT23-5 plastic package.



Optimum Technology Matching® Applied

- | | | |
|-------------------------------------|--|--------------------------------------|
| <input type="checkbox"/> Si BJT | <input checked="" type="checkbox"/> GaAs HBT | <input type="checkbox"/> GaAs MESFET |
| <input type="checkbox"/> Si Bi-CMOS | <input type="checkbox"/> SiGe HBT | <input type="checkbox"/> Si CMOS |



Functional Block Diagram

Package Style: SOT23-5

Features

- 1.6dB Noise Figure @ 1850MHz
- 1.75dB Noise Figure @ 2450MHz
- 18.0dB Gain at PCS/DCS
- 15.5dB Gain at 2.45GHz
- External Bias Control
- Extremely Small SOT23-5 Package

Ordering Information

- | | |
|-------------|----------------------------------|
| RF2365 | 3V Low Noise Amplifier |
| RF2365 PCBA | Fully Assembled Evaluation Board |

RF Micro Devices, Inc.
7625 Thorndike Road
Greensboro, NC 27409, USA

Tel (336) 664 1233
Fax (336) 664 0454
<http://www.rfmd.com>

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	-0.5 to +8.0	V _{DC}
Input RF Level	+10	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



Caution! ESD sensitive device.

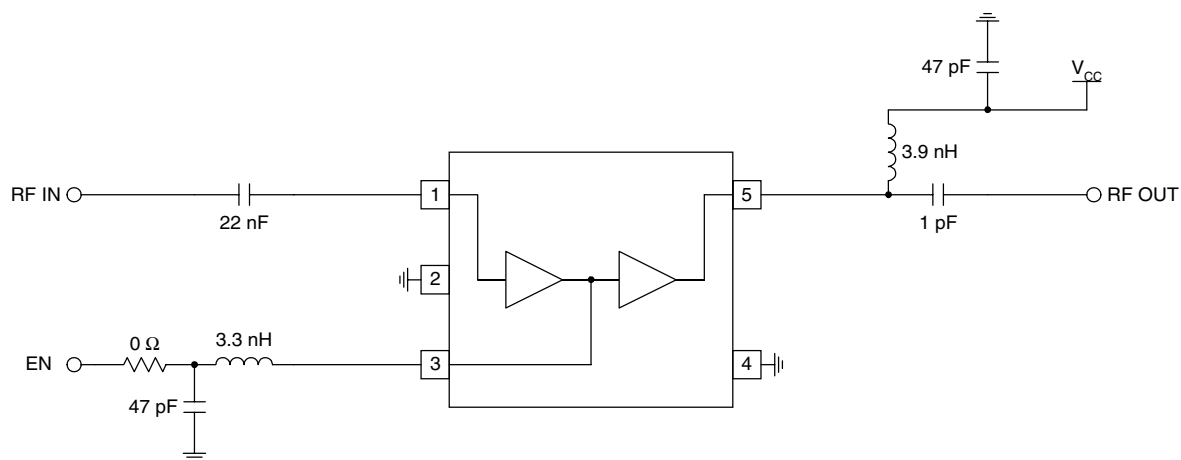
RF Micro Devices believes the furnished information is correct and accurate at the time of this printing. However, RF Micro Devices reserves the right to make changes to its products without notice. RF Micro Devices does not assume responsibility for the use of the described product(s).

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall					
RF Frequency Range	1500		2500	MHz	
PCS Performance					Schematic per 1.9GHz LNA Application Schematic, V _{PD} = 3.0 V _{CC} = 3.0V, T=25°C V _{CC} =3.0V, I _{CC} =8.0mA
Gain		18		dB	
Noise Figure		1.6		dB	
Off Mode Gain		-15		dB	V _{CC} =3.0V, V _{PD} =0
S ₁₂		25		dB	
Input IP3		-3.5		dBm	V _{CC} =3.0V, I _{CC} =5.0mA, R ₁ =150Ω (see application schematic)
		+2.0		dBm	V _{CC} =3.0V, I _{CC} =6.5mA, R ₁ =75Ω (see application schematic)
		+4.0		dBm	V _{CC} =3.0V, I _{CC} =8.0mA, R ₁ =0Ω (see application schematic)
Input VSWR		1.7			
Output VSWR		1.4			
2.4GHz Performance					Schematic per 2.4GHz LNA Application Schematic T=25°C
Gain		15.5		dB	V _{CC} =3.0V, I _{CC} =8.0mA
Noise Figure		1.75		dB	
Input IP3		+2.0		dBm	V _{CC} =3.0V, I _{CC} =8.0mA
Input VSWR		1.3			
Output VSWR		1.75			
Power Supply					T = 25 °C
Voltage (V _{CC})		3.0		V	
Current Consumption		8.0		mA	V _{CC} =3.0V, IIP3=+4.0dBm
		6.5		mA	V _{CC} =3.0V, IIP3=+2.0dBm
		5.0		mA	V _{CC} =3.0V, IIP3=-3.5dBm
Into VPD Current		TBD		mA	
Power Down			10	μA	V _{CC} =3.5V; V _{PD} ≤0.9V

Pin	Function	Description	Interface Schematic
1	RF IN	RF input pin. This pin is DC coupled.	
2	GND1	Ground connection. See evaluation board schematic notes.	
3	PD	Power down pin. This pin serves as the interstage for the 2-stage LNA. An inductor is required to pull pin 3 to V_{CC} (see application schematic). If desired, this voltage can be lowered to trade off IP3 versus $I_{CC,TOTAL}$. (See table below.)	
4	GND2	Ground connection. See evaluation board schematic notes.	
5	RF OUT	Amplifier Output pin. This pin is an open-collector output. It must be biased to either V_{CC} or pin 4 through a choke or matching inductor. This pin is typically matched to 50Ω with a shunt bias/matching inductor and series blocking/matching capacitor. Refer to application schematics.	

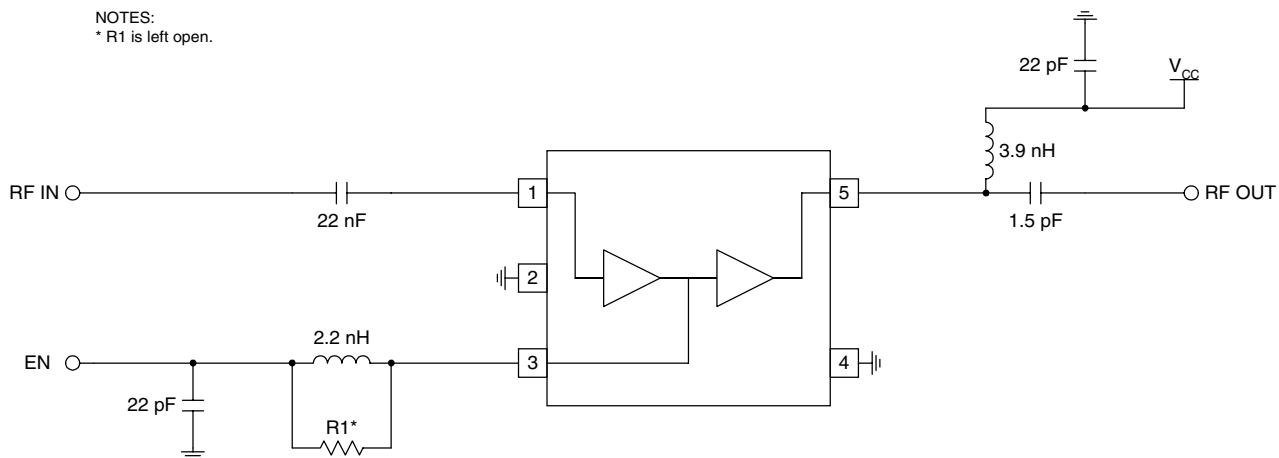
R1	IIP3	I_{CC}
0Ω	+4.0dBm	8.0mA
75Ω	+2.0dBm	6.5mA
150Ω	-3.5dBm	5.0mA

Application Schematic - 1.9GHz



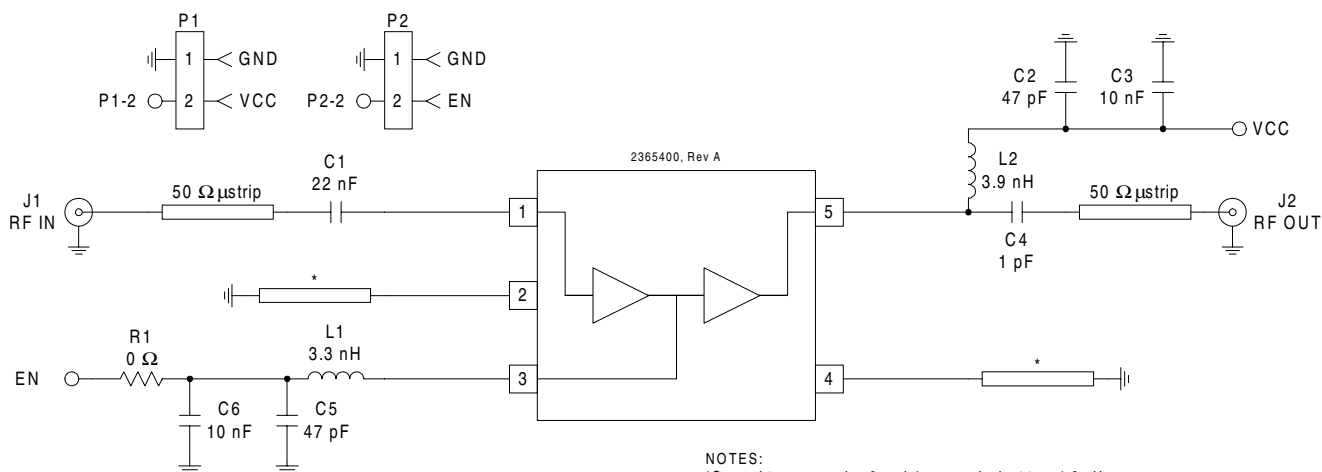
Application Schematic - 2.4GHz

NOTES:
 * R1 is left open.



Evaluation Board Schematic - 1.9GHz

(Download [Bill of Materials](http://www.rfmd.com) from www.rfmd.com.)

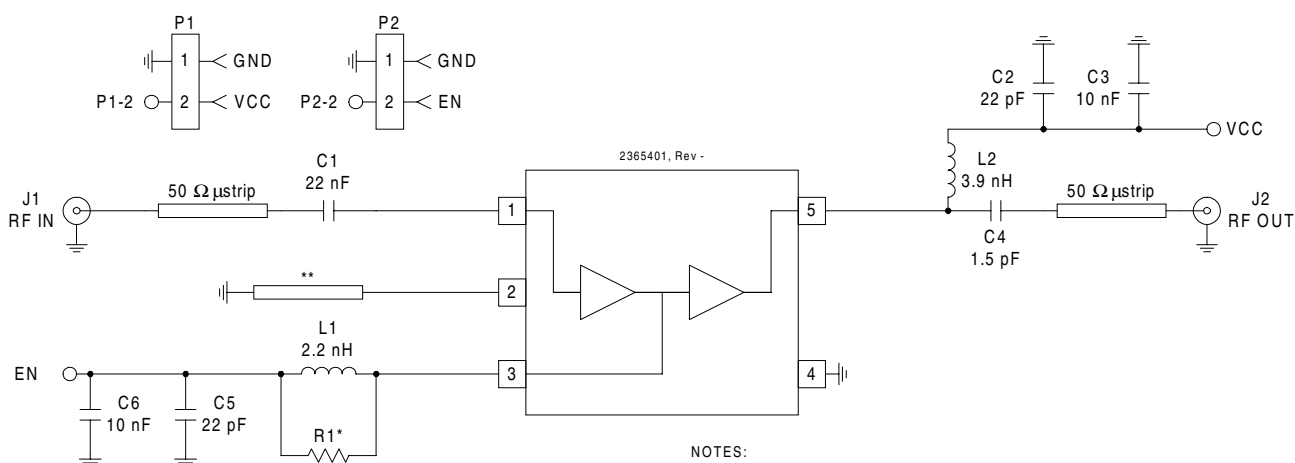


NOTES:
 *Ground traces on pins 2 and 4 are equivalent to a 1.8 nH inductor. If an inductor is not used, the dimensions are as follows:
 Length = 140 mils
 Width = 20 mils
 Height = 31 mils from the ground plane. Dielectric is FR-4.

4

GENERAL PURPOSE
AMPLIFIERS

Evaluation Board Schematic - 2.4GHz



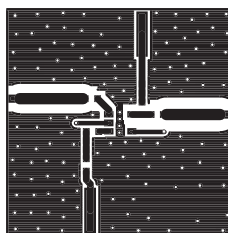
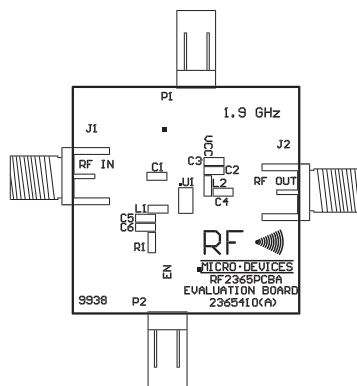
NOTES:
 * R1 is left open.
 **Ground trace on pin 2 is equivalent to a 1.0 nH inductor. If an inductor is not used, the dimensions are as follows:
 Length = 85 mils
 Width = 20 mils
 Height = 31 mils from the ground plane. Dielectric is FR-4.

Evaluation Board Layout

Board Size 1" x 1"

1.9GHz

Board Thickness 0.031"; Board Material FR-4



2.4GHz

